

Vishay Semiconductors

4-Line (Quad) ESD Protection Diode Array in LLP1010-6L

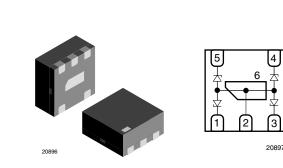
RoHS

COMPLIANT GREEN

(5-2008)

Features

- Ultra compact LLP1010-6L package
- Low package height < 0.4 mm
- 4-line ESD protection (quad)
- Low leakage current < 0.1 μA
- Low load capacitance C_D = 12 pF
- ESD-protection acc. IEC 61000-4-2 ± 15 kV contact discharge ± 17 kV air discharge
- Surge current acc. IEC 6100-4-5 IPP > 2.5 A
- Soldering can be checked by standard vision inspection. No X-ray necessary
- Pin plating NiPdAu (e4) no whisker growth
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC



Marking (example only)



Dot = Pin 1 marking

X = Date code

Y = Type code (see table below)

Ordering Information

Device name	Ordering code	Taped units per reel (8 mm tape on 7" reel)	Minimum order quantity		
VESD05A4A-HS4	VESD05A4A-HS4-GS08	5000	5000		

Package Data

Device name	Package name	Type code	Weight	Molding compound flammability rating	Moisture sensitivity level	Soldering conditions
VESD05A4A-HS4	LLP1010-6L	А	1.07 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals

** Please see document "Vishay Material Category Policy": www.vishay.com/doc?99902

Vishay Semiconductors



Absolute Maximum Ratings

Rating	Test conditions			Value	Unit
Pook pulso ourrent	BiAs-mode: each input (pin 1, 3 to 5) to ground (pin 2 and 6); acc. IEC 61000-4-5; $t_p = 8/20 \ \mu s$; single shot			2.5	А
Peak pulse current	BiSy-mode: each input (pin 1, 3 to 5) to any other input Pin 2 and 6 not connected. Acc. IEC 61000-4-5; $t_p = 8/20 \ \mu$ s;	I _{PPM}	2.5	А	
Pook pulso power	BiAs-mode: each input (pin 1, 3 to 5) to ground (pin 2 and 6); acc. IEC 61000-4-5; t _p = 8/20 μs; single shot			30	w
Peak pulse power	BiSy-mode: each input (pin 1, 3 to 5) to any other input pin. Pin 2 and 6 not connected. Acc. IEC 61000-4-5; $t_p = 8/20 \ \mu$ s; single shot			33	w
ESD immunity	Acc. IEC61000-4-2; 10 pulses BiAs-mode: each input (pin 1, 3 to 5) to ground (pin 2 and 6)	Contact discharge	V _{ESD}	± 15	kV
		Air discharge	V_{ESD}	± 17	kV
	Acc. IEC 61000-4-2 ; 10 pulses BiSy-mode: each input (pin 1, 3 to 5) to any other input pin.	Contact discharge	V _{ESD}	± 15	kV
	Pin 2 and 6 not connected.	Air discharge	V_{ESD}	± 17	kV
Operating temperature	Junction temperature			- 40 to + 125	°C
Storage temperature				- 55 to + 150	°C

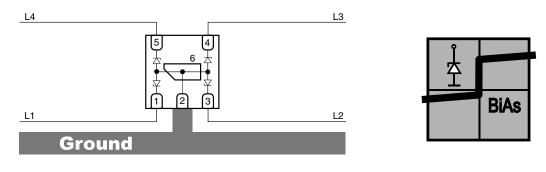
BiAs-Mode (4-line Bidirectional Asymmetrical protection mode)

With the **VESD05A4A-HS4** up to 4 signal- or data-lines (L1 to L4) can be protected against voltage transients. With pin 2 and 6 connected to ground and pin 1, 3, 4 and 5 connected to a signal- or data-line which has to be protected. As long as the voltage level on the data- or signal-line is between 0 V (ground level) and the specified **M**aximum **R**everse **W**orking **V**oltage (**V**_{**RWM**}) the protection diode between data line and ground offer a high isolation to the ground line. The protection device behaves like an open switch.

As soon as any positive transient voltage signal exceeds the break through voltage level of the protection diode, the diode becomes conductive and shorts the transient current to ground. Now the protection device behaves like a closed switch. The Clamping Voltage (V_C) is defined by the **BR**eakthrough Voltage (V_{BR}) level plus the voltage drop at the series impedance (resistance and inductance) of the protection device.

Any negative transient signal will be clamped accordingly. The negative transient current is flowing in the forward direction of the protection diode. The low Forward Voltage (V_F) clamps the negative transient close to the ground level.

Due to the different clamping levels in forward and reverse direction the **VESD05A4A-HS4** clamping behaviour is **<u>Bi</u>directional and <u>Asymmetrical</u> (BiAs**).



20898



Vishay Semiconductors

Electrical Characteristics

Ratings at 25 °C, ambient temperature unless otherwise specified

VESD05A4A-HS4

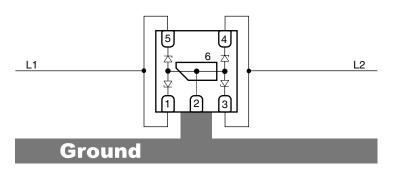
BiAs mode: each input (pin 1, 3, 4 and 5) to ground (pin 2 and/or 6)

Parameter	Test conditions/remarks	Symbol	Min.	Тур.	Max.	Unit
Protection paths	Number of line which can be protected	N _{lines}			4	lines
Reverse stand-off voltage	at I _R = 0.1 μA	V _{RWM}	5			V
Reverse current	at $V_{R} = V_{RWM} = 5 V$	I _R		< 0.01	0.1	μΑ
Reverse breakdown voltage	at I _R = 1 mA	V _{BR}	6		8	V
Clamping voltage	at I _{PP} = 2.5 A acc. IEC 61000-4-5	V _C			12	V
Forward clamping voltage	at I _F = 2.5 A acc. IEC 61000-4-5	V _F			2.5	V
Capacitance	at $V_R = 0 V$; f = 1 MHz	CD		12	15	pF
	at V _R = 2.5 V; f = 1 MHz	CD		7.5	8.5	pF

If a higher surge current or peak pulse current (I_{PP}) is needed, some protection diodes in the **VESD05A4A-HS4** can also be used in parallel in order to "multiply" the performance.

If two diodes are switched in parallel you get

- double surge power = double peak pulse current (2 x I_{PPM})
- half of the line inductance = reduced clamping voltage
- half of the line resistance = reduced clamping voltage
- double line Capacitance (2 x C_D)
- double Reverse leakage current (2 x I_R)



20900

Vishay Semiconductors

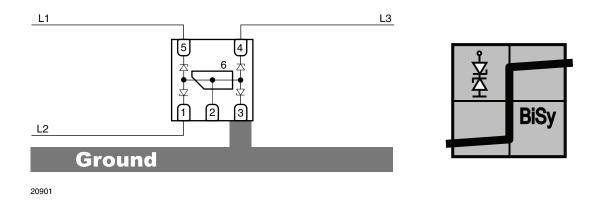


BiSy-mode (3-line Bidirectional Symmetrical protection mode)

If a bipolar symmetrical protection device is needed the **VESD05A4A-HS4** can also be used as a three-line protection device. Therefore three pins (example: pin 1, 3, and 5) has to be connected to the signal- or data-line (L1 to L3) and pin 3 to ground. Pin 2 and 6 must not be connected!

Positive and negative voltage transients will be clamped in the same way. The clamping current from one data line through the **VESD05A4A-HS4** to the ground passes one diode in forward direction and the other one in reverse direction. The **C**lamping Voltage (V_C) is defined by the **BR**eakthrough Voltage (V_{BR}) level of one diode plus the forward voltage of the other diode plus the voltage drop at the series impedances (resistances and inductances) of the protection device.

Due to the same clamping levels in positive and negative direction the **VESD05A4A-HS4** voltage clamping behaviour is also <u>**Bi**</u>directional and <u>**Sy**</u>mmetrical (**BiSy**).



Electrical Characteristics

Ratings at 25 °C, ambient temperature unless otherwise specified

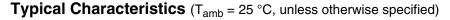
VESD05A4A-HS4

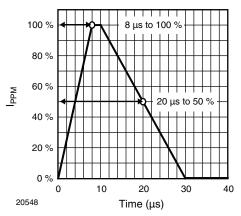
BiSy mode: each input (pin 1, 3, 4 or 5) to any other input pin connected to ground; pin 2 and 6 not connected

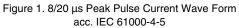
Parameter	Test conditions/remarks	Symbol	Min.	Тур.	Max.	Unit
Protection paths	Number of line which can be protected	N _{lines}			3	lines
Reverse stand-off voltage	at I _R = 0.1 μA	V _{RWM}	5.5			V
Reverse current	at $V_{R} = V_{RWM} = 5.5 V$	I _R		< 0.01	0.1	μA
Reverse breakdown voltage	at I _R = 1 mA	V_{BR}	6.5		8.7	V
Clamping voltage	at I _{PP} = 2.5 A acc. IEC 61000-4-5	V _C		11.5	13	V
Capacitance	at $V_R = 0 V$; f = 1 MHz	CD		6	8	pF
	at V _R = 2.5 V; f = 1 MHz	CD		5	7	pF



Vishay Semiconductors







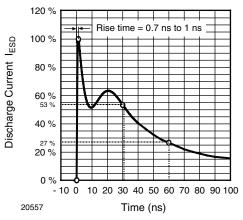


Figure 2. ESD Discharge Current Wave Form acc. IEC 61000-4-2 (330 Ω/150 pF)

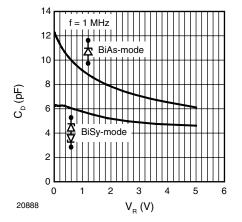


Figure 3. Typical Capacitance C_{D} vs. Reverse Voltage V_{R}

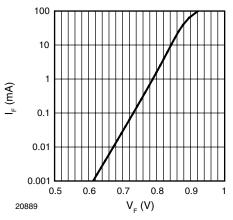
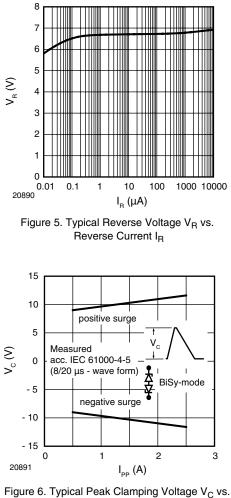


Figure 4. Typical Forward Current ${\sf I}_{\sf F}$ vs. Forward Voltage ${\sf V}_{\sf F}$



Igure 6. Typical Peak Clamping Voltage V_{C} vs Peak Pulse Current I_{PP}



Vishay Semiconductors

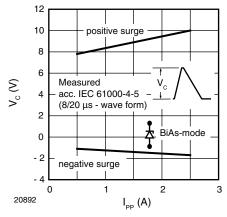


Figure 7. Typical Peak Clamping VoltageV_C vs. Peak Pulse Current I_{PP}

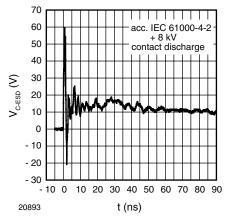
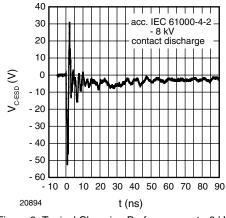
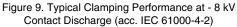


Figure 8. Typical Clamping Performance at + 8 kV Contact Discharge (acc. IEC 61000-4-2)





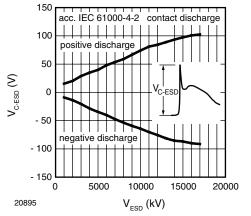
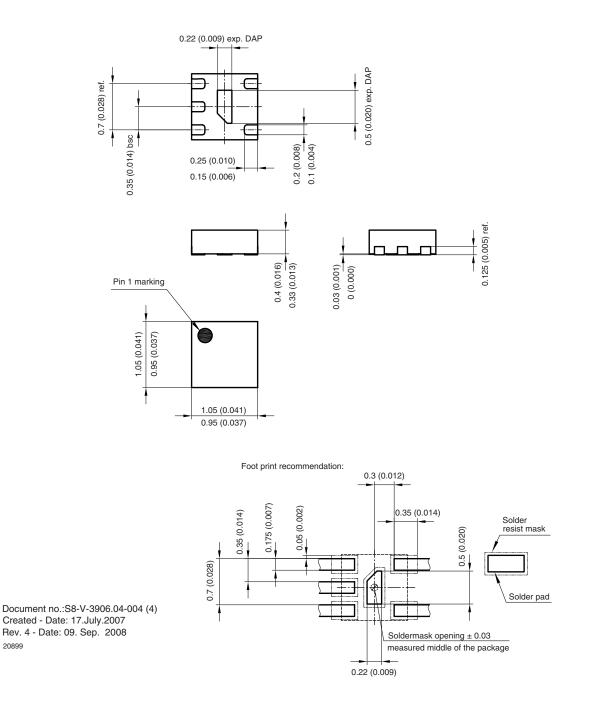


Figure 10. Typical Peak Clamping Voltage at ESD Contact Discharge (acc. IEC 61000-4-2)



Vishay Semiconductors

Package Dimensions in millimeters (inches): LLP1010-6L





Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk and agree to fully indemnify and hold Vishay and its distributors harmless from and against any and all claims, liabilities, expenses and damages arising or resulting in connection with such use or sale, including attorneys fees, even if such claim alleges that Vishay or its distributor was negligent regarding the design or manufacture of the part. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.